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## MXD8545A

## $0.1-3.0 \mathrm{GHz}$ SP4T Antenna Tuning Switch

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## General Description

The MXD8545A is a CMOS silicon-on-insulator (SOI), single-pole, four-throw (SP4T) switch. The high linearity and ruggedness performance and extremely low insertion loss makes the device an ideal choice for GSM/WCDMA/LTE handset antenna tuning application.

The MXD8545A SP4T switch is provided in a compact QFN $1.1 \mathrm{~mm} \times 1.5 \mathrm{~mm} \times 0.38 \mathrm{~mm}$ package. A functional block diagram is shown in Figure 1. The pin configuration and package are shown in Figure 2. Signal pin assignments and functional pin descriptions are provided in Table 1.

## Applications

- GSM/WCDMA/LTE band and mode switching
- Antenna tuning switch


## Features

- Broadband frequency range: 0.1 to 3.0 GHz
- Low insertion 0.50 dB @ 2.7 GHz
- High P0.1dB of 43.3 dBm
- Positive low voltage control: $\mathrm{VC}=1.0$ to 3.0 V , VDD $=2.5$ to 3.3 V , Small QFN (10-pin,
$1.1 \mathrm{~mm} \times 1.5 \mathrm{~mm} \times 0.38 \mathrm{~mm}$ ) package, MSL1


## Functional Block Diagram and Pin Function



## Application Circuit



Figure 3. MXD8545A Application Circuit
Table 1. Pin Description

| Pin No. | Name | Description | Pin No. | Name | Description |
| :--- | :--- | :--- | :--- | :--- | :--- |
| 1 | RF1 | RF port 1 | 6 | V2 | Control Logic \#2 |
| 2 | RF2 | RF port 2 | 7 | GND | Ground |
| 3 | GND | Ground | 8 | RF4 | RF port 4 |
| 4 | VDD | DC power supply | 9 | RF3 | RF port 3 |
| 5 | V1 | Control Logic \#1 | 10 | ANT | Antenna port |

## Truth Table

Table 2.

| State | V1 | V2 | RF Path |
| :---: | :---: | :---: | :---: |
| RF1 | 0 | 0 | ANT to RF1 |
| RF2 | 0 | 1 | ANT to RF2 |
| RF3 | 1 | 0 | ANT to RF3 |
| RF4 | 1 | 1 | ANT to RF4 |

Note: "1" $=1.0 \mathrm{~V}$ to 3.00 V . "0" $=0 \mathrm{~V}$ to +0.3 V .

## Recommended Operation Range

Table 3.

| Parameters | Symbol | Min | Typ | Max | Units |
| :--- | :---: | :---: | :---: | :---: | :--- |
| Operation Frequency | $\mathrm{f1}$ | 0.1 | - | 3.0 | GHz |
| Power supply | $\mathrm{V}_{\text {DD }}$ | 2.5 | 2.8 | 3.3 | V |
| Switch Control Voltage High | $\mathrm{V}_{\text {CTL H }}$ | 1.0 | 1.8 | 3.0 | V |
| Switch Control Voltage Low | $\mathrm{V}_{\text {CTL_L }}$ | 0 | 0 | 0.3 | V |

## Specifications

## Table 4.Electrical Specifications

| Parameter | Symbol | Specification |  |  | Units | Test Condition |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Typical | Max. |  |  |
| DC Specifications |  |  |  |  |  |  |
| Control voltage: |  |  |  |  |  |  |
| Low | $\mathrm{V}_{\text {cti_L }}$ | 0 | 0 | 0.3 | V |  |
| High | $\mathrm{V}_{\text {cTL_H }}$ | 1.0 | 1.8 | 3.0 | V |  |
| Supply voltage | $V_{\text {DD }}$ | 2.5 | 2.8 | 3.3 | V |  |
| Supply current | IDD |  | 75 | 110 | uA | $\mathrm{V}_{\mathrm{DD}}=2.8 \mathrm{~V}$ |
| Control current | $\mathrm{I}_{\text {CTL }}$ |  | 1 | 5 | uA | $\mathrm{V}_{\text {CTL }}=1.8 \mathrm{~V}$ |
| RF Specifications |  |  |  |  |  |  |
| Insertion loss | IL |  | 0.35 | 0.45 | dB | 0.8 to 1.0 GHz |
|  |  |  | 0.45 | 0.55 | dB | 1.0 to 2.2 GHz |
|  |  |  | 0.50 | 0.70 | dB | 2.2 to 3.0 GHz |
| Isolation | ISO | 26 | 28 |  | dB | 0.8 to 1.0 GHz |
|  |  | 22 | 24 |  | dB | 1.0 to 2.2 GHz |
|  |  | 19 | 22 |  | dB | 2.2 to 3.0 GHz |
| Return loss | $\left\|S_{11}\right\|$ |  | 20 |  | dB | 0.8 to 3.0 GHz |
| Voltage Standing Wave Ratio | VSWR |  | 1.20 |  |  | 0.8 to 3.0 GHz |
| On Resistance (RF1/2/3/4 to ANT) | Ron |  | 1.05 | 1.15 | $\Omega$ | Switch on Path |
| OFF Capacitance (RF1/2/3/4 to ANT) | Coff |  | 130 | 150 | fF | Switch off Path |
| Input 0.1 dB compression point | $\mathrm{P}_{0.1 \mathrm{~dB}}$ | +43 | +43.3 |  | dBm | 0.8 to 3.0 GHz , ANT to RF1/2/3/4 |
| Peak RF operating voltage | $V_{\text {peak }}$ |  | 45 |  | V | $\begin{aligned} & \text { f0 = } 700 \text { to } 2700 \mathrm{MHz}, \\ & 25 \% \text { duty cycle } \end{aligned}$ |
| LTE TX harmonic (RF1/2/3/4 to ANT) | $2 f 0$ |  | -80 | -70 | dBm | $\begin{aligned} & \mathrm{f0}=700 \text { to } 2700 \mathrm{MHz}, \mathrm{PIN}=+26 \\ & \mathrm{dBm} \end{aligned}$ |
|  | $3 \mathrm{f0}$ |  | -90 | -80 | dBm |  |
| GSM LB harmonic (RF1/2/3/4 to ANT) | 2 f0 |  | -60 | -50 | dBm | $\begin{aligned} & \mathrm{f0}=824 \text { to } 915 \mathrm{MHz}, \mathrm{PIN}=+35 \\ & \mathrm{dBm} \end{aligned}$ |
|  | $3 \mathrm{f0}$ |  | -60 | -50 | dBm |  |
| GSM HB harmonic (RF1/2/3/4 to ANT) | $2 \mathrm{f0}$ |  | -60 | -50 | dBm | $\begin{aligned} & \mathrm{f0}=1710 \text { to } 2690 \mathrm{MHz}, \mathrm{PIN}=+33 \\ & \mathrm{dBm} \end{aligned}$ |
|  | $3 \mathrm{f0}$ |  | -60 | -50 | dBm |  |
| Second order intermodulation | IMD2 |  | -112 | -105 | dBm | CW Carrier on RF Port, +20 dBm CW Interferer on ANT port, -15 dBm |
| Third order intermodulation | IMD3 |  | -112 | -105 | dBm | CW Carrier on RF Port, +20 dBm CW Interferer on ANT port, -15 dBm |
| Switching on time |  |  | 3.0 | 5.0 | $\mu \mathrm{s}$ | $50 \%$ VCTL to $90 \%$ RF |
| Switching off time |  |  | 3.0 | 5.0 | $\mu \mathrm{s}$ | 50\% VCTL to 10\% RF |
| Startup time |  |  | 10 | 20 | $\mu \mathrm{s}$ | Power off state to any RF switch state |

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Table 5. IMD2 Test Conditions

| Band | In-band freq | CW Carrier |  | CW Interferer |  |
| :--- | :---: | :---: | :---: | :---: | :---: |
|  | $\mathbf{M H z}$ | $\mathbf{M H z}$ | $\mathbf{d B m}$ | $\mathbf{M H z}$ | $\mathbf{d B m}$ |
| 1 Low | 2140 | 1950 | +20 | 190 | -15 |
| 1 High | 2140 | 1950 | +20 | 4090 | -15 |
| 5 Low | 881.5 | 836.5 | +20 | 45 | -15 |
| 5 High | 881.5 | 836.5 | +20 | 1718 | -15 |

## Table 6. IMD3 Test Conditions

| Band | In-band freq | CW Carrier |  | CW Interferer |  |
| :--- | :---: | :---: | :---: | :---: | :---: |
|  | $\mathbf{M H z}$ | $\mathbf{M H z}$ | $\mathbf{d B m}$ | $\mathbf{M H z}$ | $\mathbf{d B m}$ |
| 1 | 2140 | 1950 | +20 | 1760 | -15 |
| 5 | 881.5 | 836.5 | +20 | 791.5 | -15 |

## Absolute Maximum Ratings

## Table 7. Maximum ratings

| Parameters | Symbol | Minimum | Maximum | Units |
| :---: | :---: | :---: | :---: | :---: |
| Supply voltage | $V_{\text {DD }}$ | +2.5 | +3.6 | V |
| Digital control voltage | $V_{\text {cti }}$ | 0 | +3.6 | V |
| input power (RF port, 25\% DC) | Pin |  | +43.8 | dBm |
| input power (RF port, VSWR = 10:1, CW) | Pin |  | +38 | dBm |
| input power ( RF port, LTE 10M Full RB, VSWR $=10: 1, \mathrm{CW}$ ) | Pin |  | +32 | dBm |
| input power (GSM LB, CW and 50\% DC ) | Pin |  | +40 | dBm |
| $\begin{aligned} & \text { input power ( GSM HB, } \\ & \text { CW and } 50 \% \text { DC ) } \end{aligned}$ | Pin |  | +38 | dBm |
| Operating temperature | Top | -35 | +90 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature | $\mathrm{T}_{\text {STG }}$ | -55 | +150 | ${ }^{\circ} \mathrm{C}$ |
| Electrostatic Discharge Human body model (HBM), Class 2 Machine Model (MM), Class B <br> Charged device model (CDM), Class III | $\begin{aligned} & \text { ESD_HBM } \\ & \text { ESD_MM } \\ & \text { ESD_CDM } \end{aligned}$ |  | $\begin{aligned} & 1500 \\ & 150 \\ & 500 \end{aligned}$ | V |

Note: Exposure to maximum rating conditions for extended periods may reduce device reliability. There is no damage to device with only one parameter set at the limit and all other parameters set at or below their nominal value. Exceeding any of the limits listed here may result in permanent damage to the device.

## Package Outline Dimension



Figure 4. Package outline dimension

Reflow Chart


Figure 5. Recommended Lead-Free Reflow Profile
Table 8.

| Profile Parameter | Lead-Free Assembly, Convection, IR/Convection |
| :--- | :--- |
| Ramp-up rate $\left(\mathrm{TS}_{\text {max }}\right.$ to $\left.\mathrm{T}_{\mathrm{p}}\right)$ | $3^{\circ} \mathrm{C} /$ second max. |
| Preheat temperature $\left(\mathrm{TS}_{\text {min }}\right.$ to $\left.\mathrm{TS}_{\text {max }}\right)$ | $150^{\circ} \mathrm{C}$ to $200^{\circ} \mathrm{C}$ |
| Preheat time $\left(\mathrm{t}_{\mathrm{s}}\right)$ | $60-180$ seconds |
| Time above $\mathrm{TL}, 217^{\circ} \mathrm{C}\left(\mathrm{t}_{\mathrm{L}}\right)$ | $60-150$ seconds |
| Peak temperature $\left(\mathrm{T}_{\mathrm{p}}\right)$ | $260^{\circ} \mathrm{C}$ |
| Time within $5^{\circ} \mathrm{C}$ of peak temperature $\left(\mathrm{t}_{\mathrm{p}}\right)$ | $20-40$ seconds |
| Ramp-down rate | $6^{\circ} \mathrm{C} /$ second max. |
| Time $25^{\circ} \mathrm{C}$ to peak temperature | 8 minutes max. |

## ESD Sensitivity

Integrated circuits are ESD sensitive and can be damaged by static electric charge. Proper ESD protection techniques should be used when handling these devices.

## RoHS Compliant

This product does not contain lead, mercury, cadmium, hexavalent chromium, polybrominated biphenyls (PBB) and polybrominated diphenyl ethers (PBDE), and are considered RoHS compliant.

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